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Vishay Siliconix

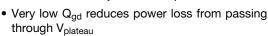
N-Channel 100 V (D-S) MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	100				
$R_{DS(on)}$ max. (Ω) at V_{GS} = 10 V	0.0040				
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 7.5 \text{ V}$	0.0045				
Q _g typ. (nC)	84				
I _D (A)	150 ^d				
Configuration	Single				

FEATURES

- TrenchFET® power MOSFET
- Maximum 175 °C junction temperature

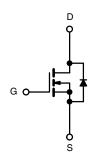




- 100 % R_a and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Switching power supply
- DC/DC converter
- Power tools
- · Motor drive switch
- DC/AC inverter
- · Battery management
- OR-ing / e-fuse



N-Channel MOSFET

ORDERING INFORMATION			
Package	TO-263		
Lead (Pb)-free and halogen-free	SUM70042E-GE3		

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-source voltage	V _{DS}	100	V			
Gate-source voltage	V _{GS}	± 20	v			
Ocalia	T _C = 25 °C	,	150 ^d			
Continuous drain current (T _J = 150 °C)	T _C = 70 °C	l _D	139	A		
Pulsed drain current (t = 100 μs)		I _{DM}	200			
Avalanche current		I _{AS}	50			
Single avalanche energy ^a	L = 0.1 mH	E _{AS}	125	mJ		
Maximum namer discination 8	T _C = 25 °C	Б	278 b	W		
Maximum power dissipation ^a	T _C = 125 °C	P _D	178 ^b	vv		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C		

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-ambient (PCB mount) ^c	R _{thJA}	40	°C/W		
Junction-to-case (drain)	R _{thJC}	0.55	C/W		

Notes

- a. Duty cycle ≤ 1 %
- b. See SOA curve for voltage derating
- c. When mounted on 1" square PCB (FR4 material)
- d. Package limited



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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_{D} = 10 \text{ mA}$	100	-	-	.,	
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	2	-	4	V	
Gate-body leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	=	-	± 250	nA	
		V _{DS} = 100 V, V _{GS} = 0 V	-	-	1	μА	
Zero gate voltage drain current	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V, T _J = 125 °C	-	-	150		
		V _{DS} = 100 V, V _{GS} = 0 V, T _J = 175 °C	-	-	5	mA	
On-state drain current a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, V_{GS} = 10 \text{ V}$	50	-	-	Α	
D	_	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	-	0.0033	0.0040	Ω	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = 7.5 V, I _D = 15 A	=	0.0036	0.0045		
Forward transconductance a	9 _{fs}	V _{DS} = 15 V, I _D = 15 A	-	60	-	S	
Dynamic ^b							
Input capacitance	C _{iss}		-	6490	-	pF	
Output capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 50 \text{ V}, f = 1 \text{ MHz}$	-	570	-		
Reverse transfer capacitance	C _{rss}		-	20	-		
Total gate charge ^c	Qg		-	84	110		
Gate-source charge ^c	Q _{gs}	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	-	33.5	-	nC	
Gate-drain charge ^c	Q _{gd}		-	9.5	-		
Gate resistance	Rg	f = 1 MHz	0.26	1.3	2.6	Ω	
Turn-on delay time ^c	t _{d(on)}		-	25	50		
Rise time ^c	t _r	$V_{DD} = 50 \text{ V}, R_L = 5 \Omega$	-	18	36		
Turn-off delay time ^c	t _{d(off)}	$I_D \cong 10 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 1 \Omega$	-	45	90	ns	
Fall time ^c	t _f		-	14	28		
Drain-Source Body Diode Ratings	and Characte	ristics ^b (T _C = 25 °C)					
Pulsed current (t = 100 μs)	I _{SM}		-	-	200	Α	
Forward voltage ^a	V _{SD}	I _F = 10 A, V _{GS} = 0 V	1	0.8	1.5	V	
Reverse recovery time	t _{rr}		1	58	116	ns	
Peak reverse recovery charge	I _{RM(REC)}		-	3.9	5.9	Α	
Reverse recovery charge	Q _{rr}	$I_F = 10 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}$	-	126	189	μC	
Reverse recovery fall time	ta		-	42	-	ns	
Reverse recovery rise time	t _b		-	16	-	119	

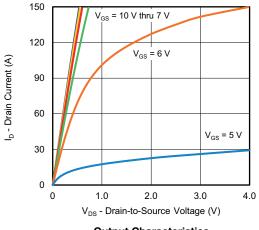
Notes

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

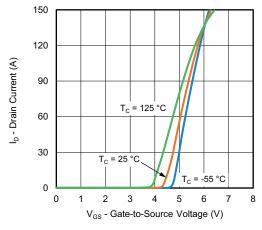
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



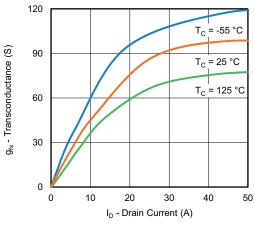
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



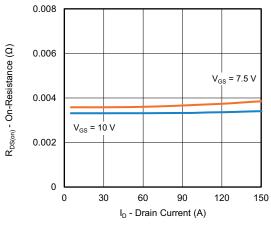
Output Characteristics



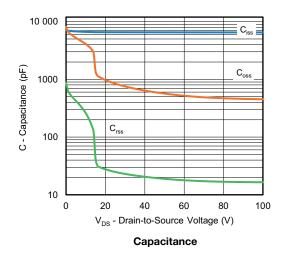
Transfer Characteristics

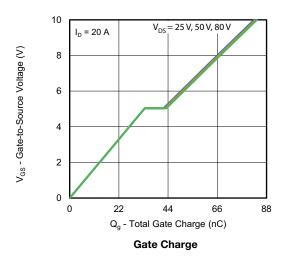


Transconductance



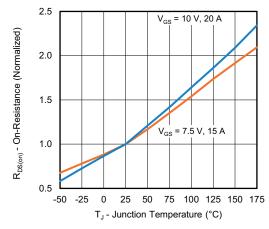
On-Resistance vs. Drain Current



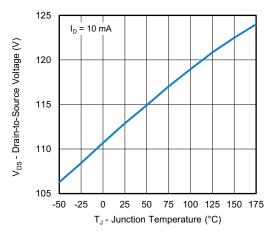




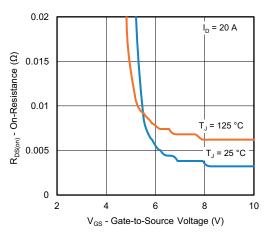
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



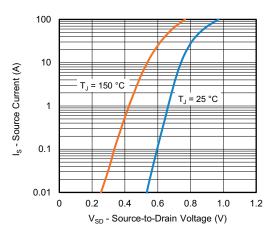
On-Resistance vs. Junction Temperature



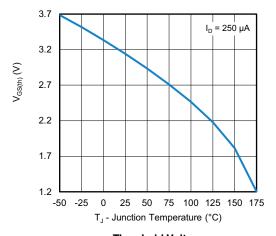
Drain Source Breakdown vs. Junction Temperature



On-Resistance vs. Gate-to-Source Voltage

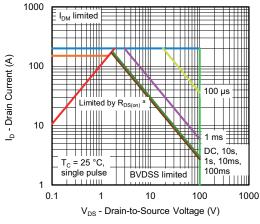


Source Drain Diode Forward Voltage





THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)





10

0.000001

0.00001

100

25 °C

0.0001

t - Time (s)

0.001

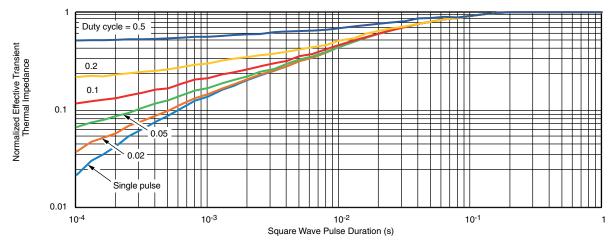
0.01

I_{DAV} - Drain Current Avalanche (A)

Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?63052.



TO-263 (D²PAK): 3-LEAD









DETAIL A (ROTATED 90°)



<u> </u>	b	+ +
≥		<u>, o</u>
0	ECTION A	1

- 1. Plane B includes maximum features of heat sink tab and plastic.
- 2. No more than 25 % of L1 can fall above seating plane by max. 8 mils.
- 3. Pin-to-pin coplanarity max. 4 mils.
- 4. *: Thin lead is for SUB, SYB. Thick lead is for SUM, SYM, SQM.
- 5. Use inches as the primary measurement.

6 This feature is for thick lead.

		INCHES		MILLIMETERS		
DIM.		MIN.	MAX.	MIN.	MAX.	
Α		0.160	0.190	4.064	4.826	
	b	0.020	0.039	0.508	0.990	
	b1	0.020	0.035	0.508	0.889	
	b2	0.045	0.055	1.143	1.397	
c*	Thin lead	0.013	0.018	0.330	0.457	
	Thick lead	0.023	0.028	0.584	0.711	
c1	Thin lead	0.013	0.017	0.330	0.431	
CI	Thick lead	0.023	0.027	0.584	0.685	
	c2	0.045	0.055	1.143	1.397	
	D	0.340	0.380	8.636	9.652	
	D1	0.220	0.240	5.588	6.096	
	D2	0.038	0.042	0.965	1.067	
	D3	0.045	0.055	1.143	1.397	
	D4	0.044	0.052	1.118	1.321	
	Е	0.380	0.410	9.652	10.414	
	E1	0.245	-	6.223	-	
	E2	0.355	0.375	9.017	9.525	
	E3	0.072	0.078	1.829	1.981	
	е	0.100	BSC	2.54 BSC		
	K	0.045	0.055	1.143	1.397	
	L	0.575	0.625	14.605	15.875	
L1		0.090	0.110	2.286	2.794	
L2		0.040	0.055	1.016	1.397	
L3		0.050	0.070	1.270	1.778	
	L4	0.010 BSC		0.254 BSC		
	М	-	0.002	-	0.050	
ECN: T13-0707-Rev. K, 30-Sep-13						

DWG: 5843





RECOMMENDED MINIMUM PADS FOR D²PAK: 3-Lead



Recommended Minimum Pads Dimensions in Inches/(mm)

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